

TMUXHS4512 1.8V 6-Channel 20Gbps Differential 2:1 Mux / 1:2 Demux

1 Features

- Supports USB4 up to 20Gbps, DisplayPort 1.4/2.1 up to UHBR20
- Data rate support up to 20Gbps
- High-speed path supports common-mode voltage range of 0V to 1.0V
- Low R_{ON} of 8.8 Ω typical for high-speed data pins
- -3dB differential BW of 13.0GHz for high-speed data pins
- Excellent dynamic characteristics at 10GHz:
 - Insertion loss: -2.5dB
 - Return loss: -13dB
 - Cross talk: -30dB
- All sideband signals can pass-through up to 1.8V levels and are 5.5V tolerant
- Support 1.2V, 1.8V and 3.3V control logic
- Single supply voltage of 1.8V
- Low active (500 μ A) and standby power (2 μ A)
- I_{OFF} protection that prevents current leakage when supply rail collapsed ($V_{CC} = 0V$)
- Temperature range: -40°C to 125°C
- Package: 40-pin, 3mm x 6mm, 0.4mm pitch WQFN

2 Applications

- [PC and notebooks](#)
- [Gaming, Home theater & entertainment and TV](#)
- [Data center and enterprise computing](#)
- [Medical applications](#)
- [Test and measurements](#)
- [Factory automation and control](#)
- [Aerospace and defense](#)
- [Electronic point of sale \(EPOS\)](#)
- [Wireless infrastructure](#)

3 Description

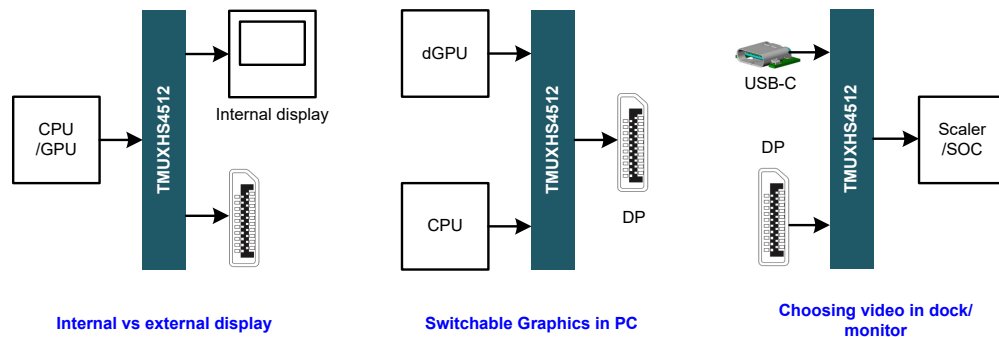
The TMUXHS4512 is a high-speed bidirectional passive switch in mux or demux configurations. The device is protocol agnostic supporting many applications including USB4, Thunderbolt3/4, and DisplayPort 1.4 / 2.1. The TMUXHS4512 is a generic analog differential passive mux or demux that works for many high-speed differential interfaces with data rates up to 20Gbps. The TMUXHS4512 high-speed channels support differential signaling and single-ended signaling as long as the single-ended signals do not violate $V_{P-N_ABS\text{MAX}}$ parameter. The sideband channels are 5V tolerant and support single-ended and differential signaling such as I²C, UART, DisplayPort AUX, and USB2, just to name a few. The dynamic characteristics of the high-speed channel allows high-speed switching with minimal attenuation to the signal eye diagram and with very little added jitter. The silicon design of the device is optimized for excellent frequency response at higher frequency spectrum of the signals. The device supports differential signaling with common-mode voltage range (CMV) of 0V to 1.0V in the Dxx datapaths.

The TMUXHS4512 consumes very low active power of 500 μ A. The device also offers a power-down mode in which all channels become Hi-Z and the device operates with minimal power of just 2 μ A.

Package Information

| PART NUMBER | TEMPERATURE | PACKAGE ⁽¹⁾ | PACKAGE SIZE ⁽²⁾ |
|-------------|--|------------------------|-----------------------------|
| TMUXHS4512 | $T_A = 0^\circ\text{C}$ to 105°C | RET (WQFN, 40) | 6mm x 3mm |
| TMUXHS4512I | $T_A = -40^\circ\text{C}$ to 125°C | | |

- (1) For all available packages, see [Section 11](#).
- (2) The package size (length x width) is a nominal value and includes pins, where applicable.



Simplified Use Cases

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4 Pin Configuration and Functions

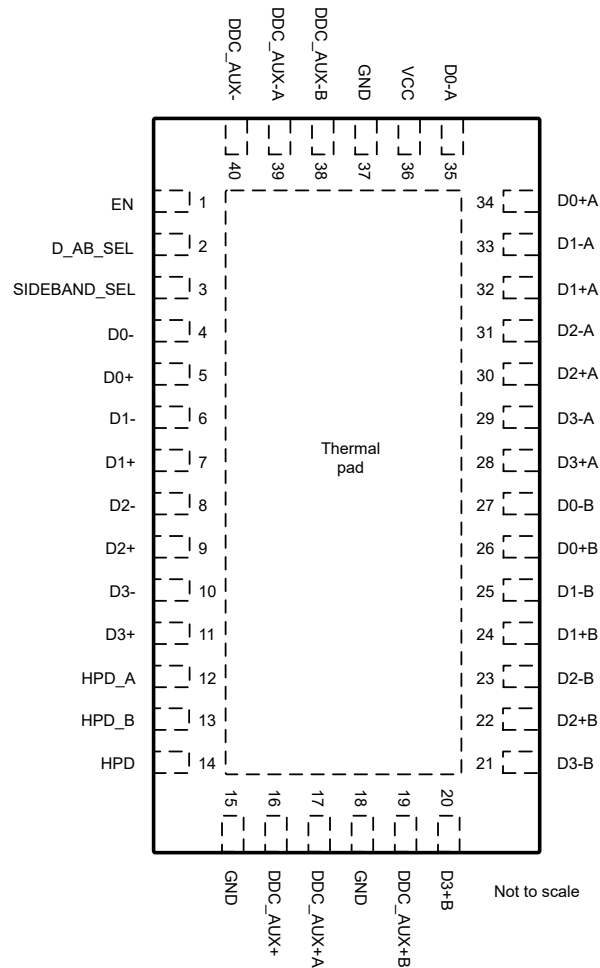


Figure 4-1. RET Package 40-Pin WQFN With Exposed Thermal Pad (Top View)

Table 4-1. Pin Functions

| PIN | | TYPE | DESCRIPTION |
|--------------|-----|------|--|
| NAME | NO. | | |
| EN | 1 | I | Device Enable L: Device Disabled. All data and sideband signals in Hi-Z. H: Device Enabled. All data and sideband signals selected by D_AB_SEL and SIDEBAND_SEL are enabled. |
| D_AB_SEL | 2 | I | Selects between high-speed datapath A and B. L: High-speed datapath A H: High-speed datapath B |
| SIDEBAND_SEL | 3 | I | Selects between sideband path A and B L: Sideband path A H: Sideband path B |
| D0- | 4 | I/O | Common Port, Channel 0, -ve signal |
| D0+ | 5 | I/O | Common Port, Channel 0, +ve signal |
| D1- | 6 | I/O | Common Port, Channel 1, -ve signal |
| D1+ | 7 | I/O | Common Port, Channel 1, +ve signal |
| D2- | 8 | I/O | Common Port, Channel 2, -ve signal |

Table 4-1. Pin Functions (continued)

| PIN | | TYPE | DESCRIPTION |
|-----------|----------|-------|--|
| NAME | NO. | | |
| D2+ | 9 | I/O | Common Port, Channel 2, +ve signal |
| D3- | 10 | I/O | Common Port, Channel 3, -ve signal |
| D3+ | 11 | I/O | Common Port, Channel 3, +ve signal |
| HPD_A | 12 | I/O | Port A, Hot Plug Detect sideband signal |
| HPD_B | 13 | I/O | Port B, Hot Plug Detect sideband signal |
| HPD | 14 | I/O | Common Port, Hot Plug Detect sideband signal |
| GND | 15 | GND | Ground |
| DDC_AUX+ | 16 | I/O | Common Port, DDC or AUX sideband signal |
| DDC_AUX+A | 17 | I/O | Port A, DDC or AUX sideband signal |
| GND | 18 | GND | Ground |
| DDC_AUX+B | 19 | I/O | Port B, DDC or AUX sideband signal |
| D3+B | 20 | I/O | Port B, Channel 3, +ve signal |
| D3-B | 21 | I/O | Port B, Channel 3, -ve signal |
| D2+B | 22 | I/O | Port B, Channel 2, +ve signal |
| D2-B | 23 | I/O | Port B, Channel 2, -ve signal |
| D1+B | 24 | I/O | Port B, Channel 1, +ve signal |
| D1-B | 25 | I/O | Port B, Channel 1, -ve signal |
| D0+B | 26 | I/O | Port B, Channel 0, +ve signal |
| D0-B | 27 | I/O | Port B, Channel 0, -ve signal |
| D3+A | 28 | I/O | Port A, Channel 3, +ve signal |
| D3-A | 29 | I/O | Port A, Channel 3, -ve signal |
| D2+A | 30 | I/O | Port A, Channel 2, +ve signal |
| D2-A | 31 | I/O | Port A, Channel 2, -ve signal |
| D1+A | 32 | I/O | Port A, Channel 1, +ve signal |
| D1-A | 33 | I/O | Port A, Channel 1, -ve signal |
| D0+A | 34 | I/O | Port A, Channel 0, +ve signal |
| D0-A | 35 | I/O | Port A, Channel 0, -ve signal |
| VCC | 36 | Power | Supply Voltage |
| GND | 37 | GND | Ground |
| DDC_AUX-B | 38 | I/O | Port B, DDC or AUX sideband signal |
| DDC_AUX-A | 39 | I/O | Port A, DDC or AUX sideband signal |
| DDC_AUX- | 40 | I/O | Common Port, DDC or AUX sideband signal |
| GND | PowerPad | GND | Ground |

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

| | | | MIN | MAX | UNIT |
|---|---|----------------------------------|------|-----|------|
| V _{CC} _{ABSM} AX | Supply voltage range | | -0.5 | 2.5 | V |
| V _{I/O} - ABSMAX | Analog voltage range ^{(2) (3) (4)} | All high-speed data I/O pins | -0.5 | 4.0 | V |
| V _{I/O} - ABSMAX | Analog voltage range ^{(2) (3) (4)} | All sideband ⁽⁵⁾ pins | -0.5 | 6.0 | V |
| V _{IN} - ABSMAX | Digital input voltage range ^{(2) (3)} | All control pins ⁽⁶⁾ | -0.5 | 5.0 | V |
| V _P - N _{ABSMAX} | Absolute value of positive pin minus negative pin | All high-speed data I/O pins | | 0.8 | V |
| T _{Jmax} | Maximum junction temperature TMUXHS4512 | | 0 | 105 | °C |
| T _{Jmax} | Maximum junction temperature TMUXHS4512I | | -40 | 125 | °C |
| T _{stg} | Storage temperature range | | -65 | 150 | °C |

- (1) Operation outside the *Absolute Maximum Ratings* may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under *Recommended Operating Conditions*. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.
- (2) All voltages are with respect to ground, unless otherwise specified.
- (3) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- (4) V_I and V_O are used to denote specific conditions for V_{I/O}.
- (5) Sideband pins: DDC_AUX+A, DDC_AUX-A, HPD_A, DDC_AUX+B, DDC_AUX-B, HPD_B, DDC_AUX+, DDC_AUX-, HPD
- (6) Control pins: D_AB_SEL, SIDEBAND_SEL, EN

5.2 ESD Ratings

| | | | VALUE | UNIT |
|--------------------|-------------------------|--|-------|------|
| V _(ESD) | Electrostatic discharge | Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, ⁽¹⁾ | ±1500 | V |
| | | Charged device model (CDM), per ANSI/ESDA/JEDEC JS-002, ⁽²⁾ | ±750 | |

- (1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

| | | MIN | TYP | MAX | UNIT |
|---------------------|---|------|-----|-----------------|------|
| V _{CC} | Supply voltage | 1.62 | 1.8 | 1.98 | V |
| V _{I/O,CM} | Input/Output common mode voltage (data pins) | 0 | | 1 | V |
| V _{I/O} | Input/Output voltage data pins | 0 | | 1.4 | V |
| V _{I/O} | Input/Output voltage sideband ⁽²⁾ pins | 0 | | 1.8 | V |
| V _{IN} | Digital input voltage (control ⁽³⁾ pins) | 0 | | V _{CC} | V |
| DR | Data rate for differential signals | | | 20 | Gbps |
| T _A | Operating ambient temperature TMUXHS4512 | 0 | | 105 | °C |
| T _A | Operating ambient temperature TMUXHS4512I | -40 | | 125 | °C |
| T _J | Operating junction temperature TMUXHS4512 | 0 | | 110 | °C |
| T _J | Operating junction temperature TMUXHS4512I | -40 | | 125 | °C |

- (1) All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. For more information, see [Implications of Slow or Floating CMOS Inputs](#) application note.
- (2) Sideband pins: DDC_AUX+A, DDC_AUX-A, HPD_A, DDC_AUX+B, DDC_AUX-B, HPD_B, DDC_AUX+, DDC_AUX-, HPD
- (3) Control pins: D_AB_SEL, SIDEBAND_SEL, EN

5.4 Thermal Information

| THERMAL METRIC ⁽¹⁾ | | TMUXHS4512 | |
|-------------------------------|--|------------|------|
| | | RET | |
| | | 40 PINS | |
| | | | UNIT |
| R _{θJA} | Junction-to-ambient thermal resistance | 33.0 | °C/W |
| R _{θJC(top)} | Junction-to-case (top) thermal resistance | 25.4 | °C/W |
| R _{θJB} | Junction-to-board thermal resistance | 12.2 | °C/W |
| ψ _{JT} | Junction-to-top characterization parameter | 0.8 | °C/W |
| ψ _{JB} | Junction-to-board characterization parameter | 12.2 | °C/W |
| R _{θJC(bot)} | Junction-to-case (bottom) thermal resistance | 3.1 | °C/W |

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application note.

5.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

| PARAMETER ^{(3) (4)} | | | TEST CONDITIONS ⁽¹⁾ | MIN | TYP ⁽²⁾ | MAX | UNIT |
|--|---|---|--|------|--------------------|-----|------|
| DC Characteristics (data and sideband) | | | | | | | |
| R _{ON-D} | ON-state resistance | All data pins; | V _{CM} = 0V to 1V; I _{I/O} = -10mA; VCC = 1.8V ±10%; 0 to 85°C; | 8.8 | 11 | | Ω |
| | | | V _{CM} = 0V to 1V; I _{I/O} = -10mA; VCC = 1.8V ±10%; -40 to 125°C; | 8.8 | 12 | | Ω |
| R _{ON-SB} | ON-state resistance | All sideband pins; | V _{I/O} = 0V to VCC; I _{I/O} = -10mA; VCC = 1.8V ±10%; 0 to 85°C; | 8.5 | 12.5 | | Ω |
| | | | V _{I/O} = 0V to VCC; I _{I/O} = -10mA; VCC = 1.8V ±10%; -40 to 125°C; | 8.5 | 13 | | Ω |
| R _{ON-SB-3P6V} | ON-state resistance | All sideband pins; | V _{I/O} = 3.6V; I _{I/O} = -10mA; VCC = 1.8V ±10%; -40 to 125°C; | 120 | 160 | | Ω |
| C _{ON-SB-1M} | Sideband ON capacitance to GND | | f = 1MHz; | | | 7 | pF |
| C _{OFF-SB-1M} | Sideband Off capacitance to GND | | f = 1MHz; | | | 4.5 | pF |
| I _{IH-D} | Input current for high-speed data pair | All selected data pins. Leakage for each high-speed pair. | EN = H; V _{I/O} = 1.4V; VCC = 1.8V ±10%; | | | 1.5 | μA |
| | | All non-selected data pins. Leakage for each high-speed pair. | EN = H; V _{I/O} = 1.4V; VCC = 1.8V ±10%; | | | 35 | μA |
| I _{IH-SB} | Input current for sideband | All selected sideband pins. | EN = H; V _{I/O} = 1.8V; VCC = 1.8V ±10%; | | | 2.5 | μA |
| | | All non-selected sideband pins. | EN = H; V _{I/O} = 1.8V; VCC = 1.8V ±10%; | | | 1 | μA |
| I _{OFF-DAB} | Leakage under power off (failsafe current) | All data pins | VCC = 0V; V _{I/O} = 0V to 1.4V; | -8 | | 15 | μA |
| I _{OFF-SB} | Leakage under power off (failsafe current) | All sideband pins | VCC = 0V; V _{I/O} = 0V to 5.5V; | -1 | | 5 | μA |
| Control Inputs (SIDEBAND_SEL, D_AB_SEL, EN) | | | | | | | |
| V _{IH-CTRL} | High-level input voltage for control pins | Per pin for all control pins. | VCC = 1.8V ±10%; | 1.0 | | | V |
| V _{IL-CTRL} | Low-level input voltage for control pins | Per pin for all control pins. | VCC = 1.8V ±10%; | | | 0.3 | V |
| I _{IH-CTRL} | Input high leakage current for control pins | Per pin for all control pins. | VCC = 1.98V; V _{IN} = 1.98V; | -0.1 | | 0.1 | μA |
| I _{IL-CTRL} | Input low leakage current for control pins | Per pin for all control pins. | VCC = 1.98V; V _{IN} = 0V; | -0.1 | | 0.1 | μA |
| I _{OFF-CTRL} | Leakage under power off (failsafe current) | Per pin for all control pins. | VCC = 0V; V _{IN} = 0V or 1.98V; | -0.1 | | 0.1 | μA |
| C _{IN-CTRL} | Input capacitance | Per pin for all control pins. | f = 1MHz; | | | 5 | pF |
| Power Supply | | | | | | | |

over operating free-air temperature range (unless otherwise noted)

| PARAMETER ^{(3) (4)} | | | TEST CONDITIONS ⁽¹⁾ | MIN | TYP ⁽²⁾ | MAX | UNIT |
|------------------------------|---------------------------------------|---------------------------------------|--------------------------------|-----|--------------------|-----|------|
| I _{CC} | VCC supply current in active mode | VCC supply current in active mode | EN = H; V _{CM} = 1V | | | 500 | μA |
| I _{CC-PD} | VCC supply current in power-down mode | VCC supply current in power-down mode | EN = L; V _{CM} = 1V | | 0.07 | 2 | μA |

(1) V_I, V_O, I_I, and I_O refer to data and sideband I/O pins. V_{IN} refers to the control inputs.

(2) All typical values are at V_{CC} = 1.8V (unless otherwise noted), T_A = 25°C.

(3) Sideband pins: DDC_AUX+A, DDC_AUX-A, HPD_A, DDC_AUX+B, DDC_AUX-B, HPD_B, DDC_AUX+, DDC_AUX-, HPD

(4) Control pins: D_AB_SEL, SIDEBAND_SEL, EN

5.6 High-Speed Performance Parameters

over recommended operation free-air temperature range, (unless otherwise noted). For all data pins. R_L = 50Ω where applicable.

| PARAMETER | | TEST CONDITIONS | MIN | TYP ⁽¹⁾ | MAX | UNIT |
|-------------------|---|-----------------------|-----|--------------------|-----|------|
| BW _{SB} | Sideband pins differential bandwidth (–3dB from DC) | | | 2.0 | | GHz |
| BW _{HS} | High-speed pins differential bandwidth (–3dB from DC) | | | 13 | | GHz |
| IL _{DAB} | Differential insertion loss | At 100MHz; VCM = 0V; | | –0.7 | | dB |
| | | At 1.7GHz; VCM = 0V; | | –1.0 | | dB |
| | | At 2.7GHz; VCM = 0V; | | –1.1 | | dB |
| | | At 4.0GHz; VCM = 0V; | | –1.2 | | dB |
| | | At 6.0GHz; VCM = 0V; | | –1.6 | | dB |
| | | At 10.0GHz; VCM = 0V; | | –2.5 | | dB |
| RL _{DAB} | Differential return loss | At 100MHz; VCM = 0V; | | –23 | | dB |
| | | At 1.7GHz; VCM = 0V; | | –22 | | dB |
| | | At 2.7GHz; VCM = 0V; | | –20 | | dB |
| | | At 4.0GHz; VCM = 0V; | | –19 | | dB |
| | | At 6.0GHz; VCM = 0V; | | –18 | | dB |
| | | At 10.0GHz; VCM = 0V; | | –13 | | dB |
| Xtalk | Differential crosstalk | At 100MHz; VCM = 0V; | | –66 | | dB |
| | | At 1.7GHz; VCM = 0V; | | –40 | | dB |
| | | At 2.7GHz; VCM = 0V; | | –37 | | dB |
| | | At 4.0GHz; VCM = 0V; | | –44 | | dB |
| | | At 6.0GHz; VCM = 0V; | | –45 | | dB |
| | | At 10.0GHz; VCM = 0V; | | –30 | | dB |
| OISO | Differential off isolation | At 100MHz; VCM = 0V; | | –65 | | dB |
| | | At 1.7GHz; VCM = 0V; | | –37 | | dB |
| | | At 2.7GHz; VCM = 0V; | | –33 | | dB |
| | | At 4.0GHz; VCM = 0V; | | –30 | | dB |
| | | At 6.0GHz; VCM = 0V; | | –27 | | dB |
| | | At 10.0GHz; VCM = 0V; | | –23 | | dB |

(1) All Typical Values are at V_{CC} = 1.8V (unless otherwise noted), T_A = 25°C.

5.7 Switching Characteristics

| PARAMETER | | MIN | TYP | MAX | UNIT |
|------------------------------|---------------------------------------|---------------------|-----|-----|------|
| Device Switching Time | | | | | |
| t _{SW_POWER_ON} | Device power ON time | EN pin from L to H; | | 200 | μs |
| t _{SW_POWER_OFF} | Device power OFF time | EN pin from H to L; | | 550 | ns |
| High Speed Pins | | | | | |
| t _{PD} | Switch differential propagation delay | f = 1GHz | 60 | | ps |

| PARAMETER | | | MIN | TYP | MAX | UNIT |
|-----------------------|--|---|-----|-----|-----|------|
| t _{SW_AB} | Switching time from A to B | Measured from 50% of select to 50% of VOH/VOL | | | 60 | μs |
| t _{SW_BA} | Switching time from B to A | Measured from 50% of select to 50% of VOH/VOL | | | 60 | μs |
| t _{SK_INTRA} | Intra-pair output skew between + and - pins for same channel | f = 1GHz | | 1.8 | 6 | ps |
| t _{SK_INTER} | Inter-pair output skew between channels | f = 1GHz | | | 9 | ps |
| Sideband Pins | | | | | | |
| t _{PD-SB} | Switch single-ended propagation delay | f = 1MHz | | | 250 | ps |
| t _{SW-SB_AB} | Switching time from A to B | Measured from 50% of select to 50% of VOH/VOL | | | 20 | μs |
| t _{SW-SB_BA} | Switching time from B to A | Measured from 50% of select to 50% of VOH/VOL | | | 20 | μs |
| t _{SK-SB} | Output skew between DDC_AUX+ and DDC_AUX- pins | f = 1MHz | | | 8 | ps |

5.8 Typical Characteristics

Data taken from a single unit under nominal power supply and temperature conditions with $V_{I/O,CM}$ at 0V.

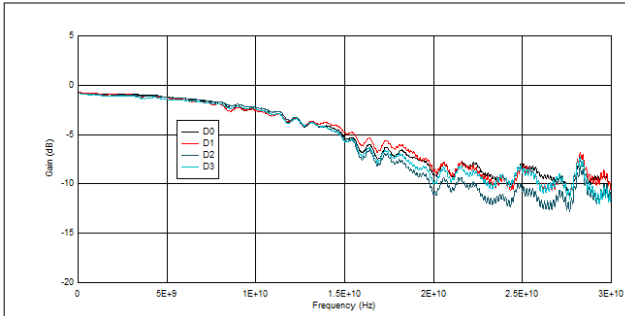


Figure 5-1. Differential Insertion Loss for port A

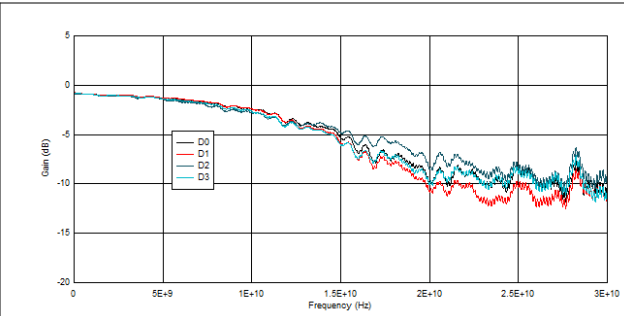


Figure 5-2. Differential Insertion Loss for port B

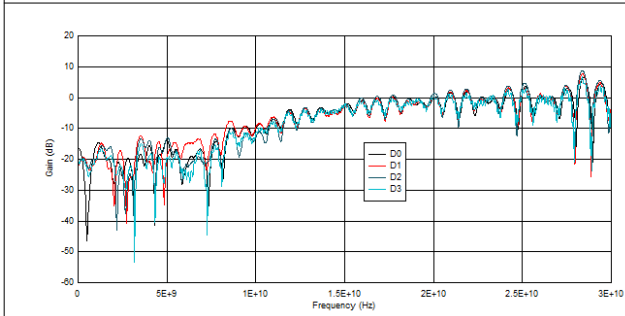


Figure 5-3. Input Differential Return Loss when port A is selected

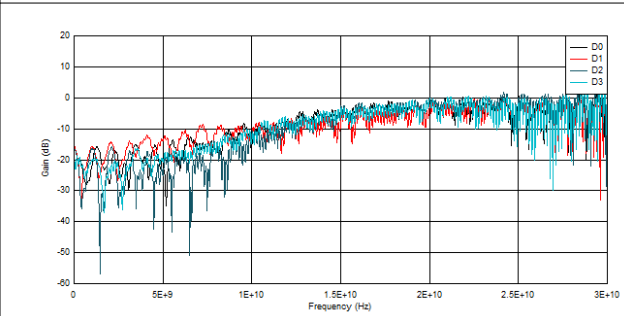


Figure 5-4. Output Differential Return Loss when port A is selected

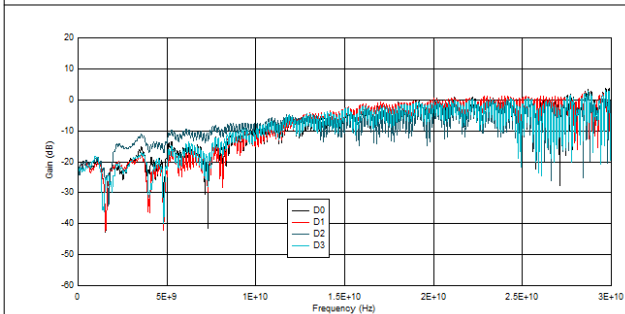


Figure 5-5. Output Differential Return Loss when port B is selected

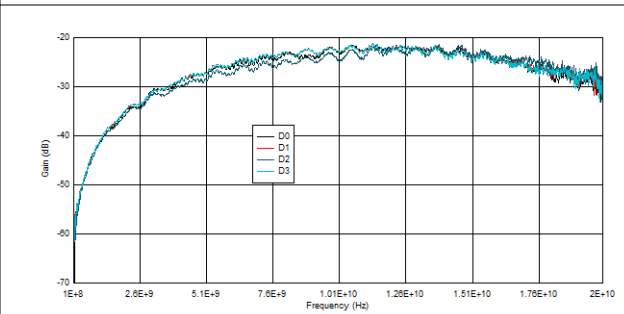


Figure 5-6. Off-State Isolation (OISO) for port A

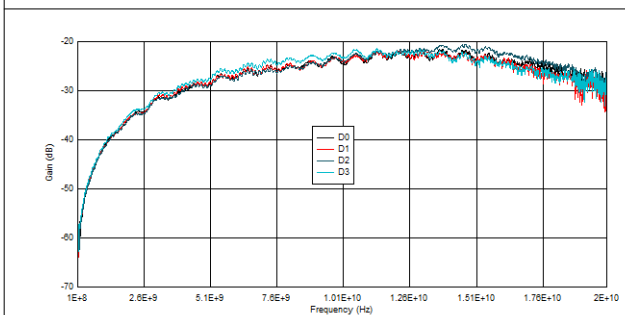


Figure 5-7. Off-State Isolation (OISO) for port B

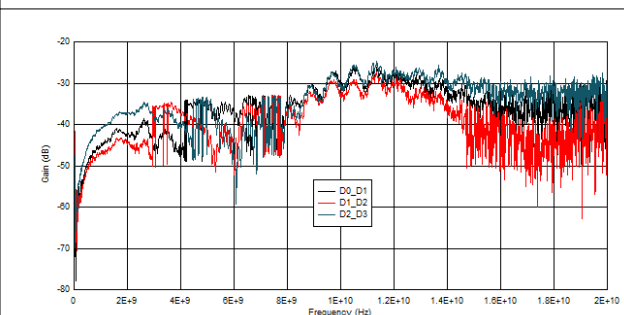
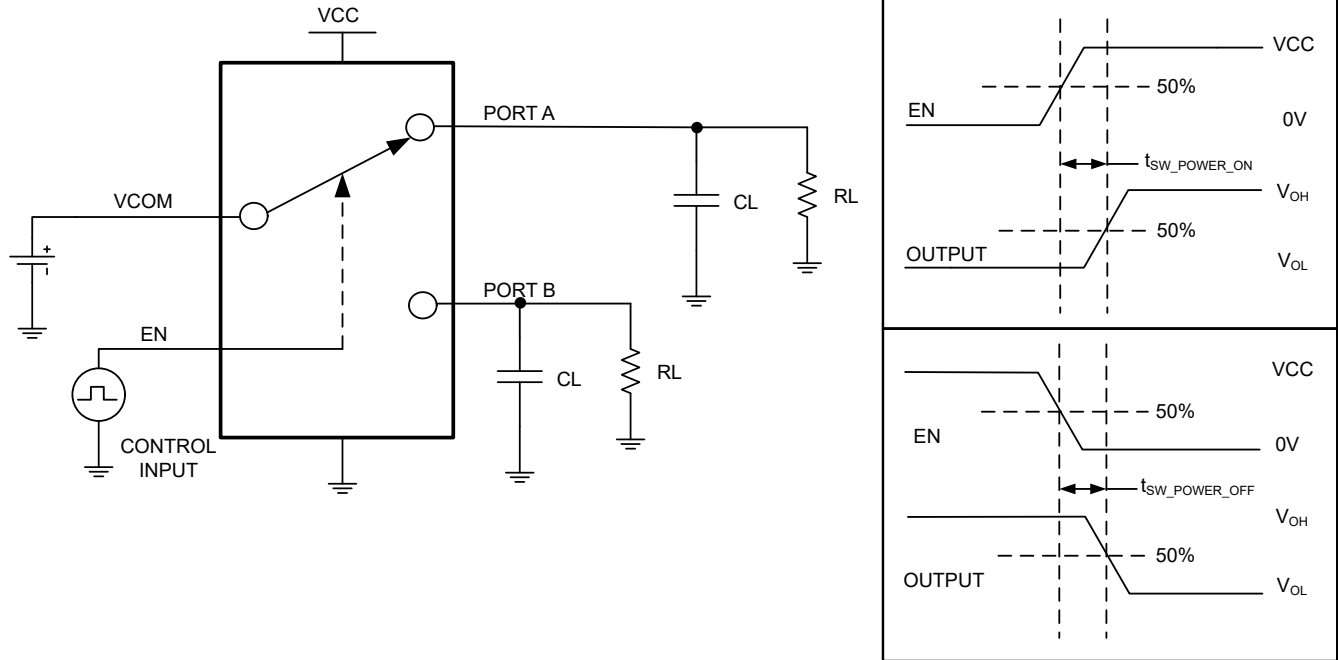


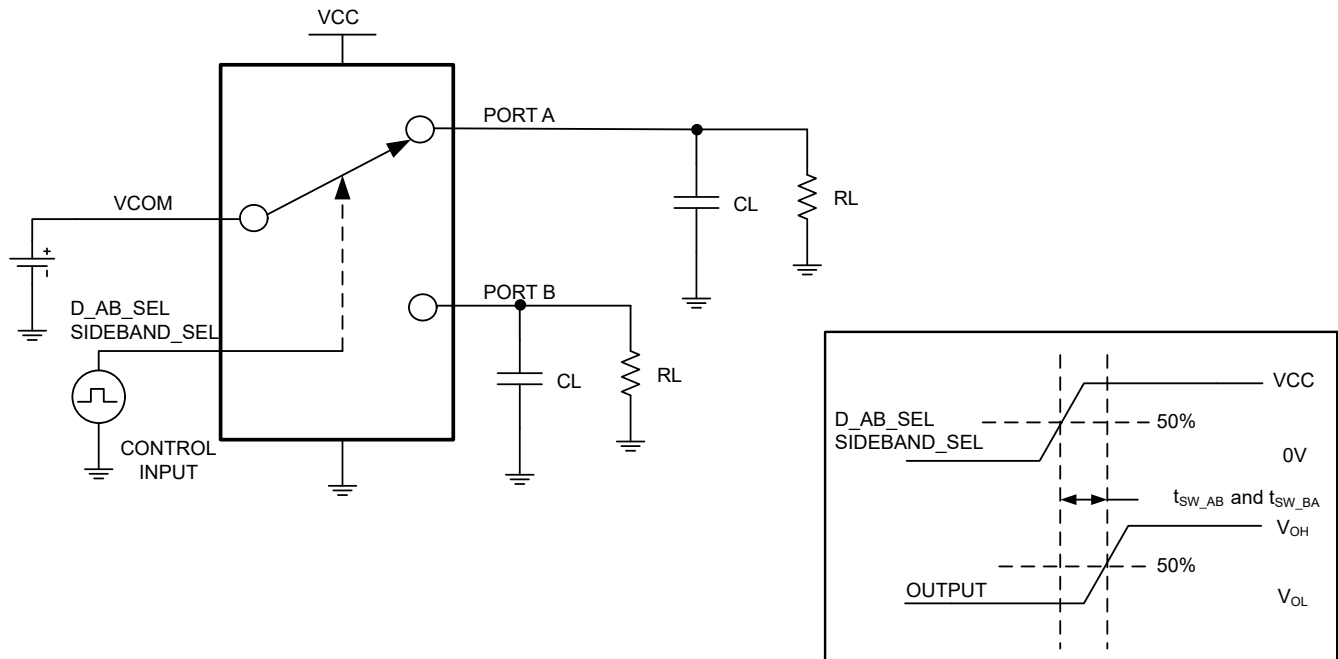
Figure 5-8. Crosstalk (Xtalk) between channels on common port side

6 Parameter Measurement Information



NOTE: $R_L = 10k\Omega$; $V_{COM} = V_{CC}$; $C_L = 1pF$

Figure 6-1. Switch Turn-On Time ($t_{sw_POWER_ON}$ and $t_{sw_POWER_OFF}$)



$R_L = 10k\Omega$; $V_{COM} = V_{CC}$; $C_L = 1pF$

Figure 6-2. Switching Time Between Channels (t_{sw_AB} and t_{sw_BA})

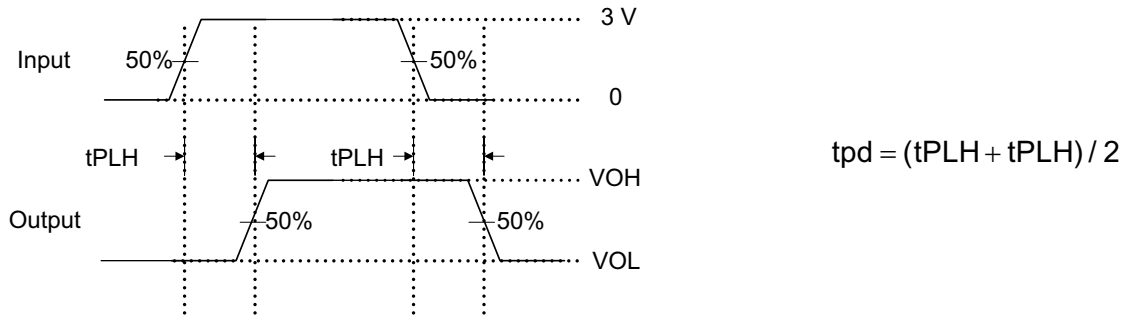


Figure 6-3. Propagation Delay (t_{pd})

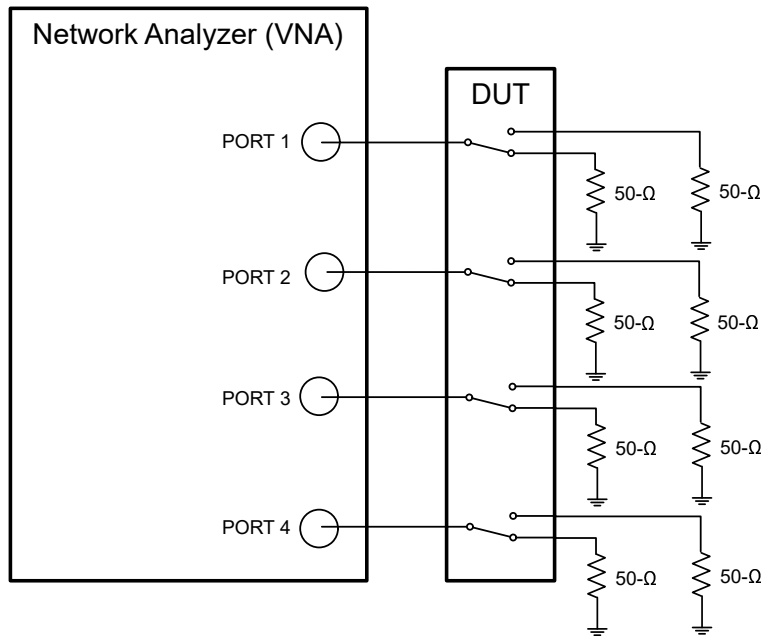


Figure 6-4. Crosstalk (Xtalk)

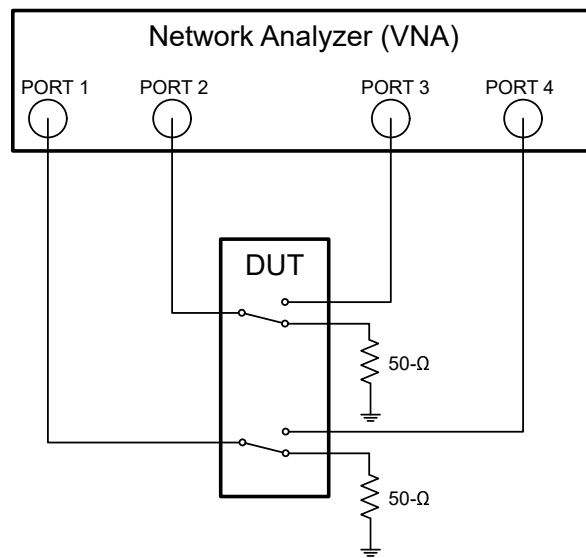


Figure 6-5. Differential Off-Isolation (OISO)

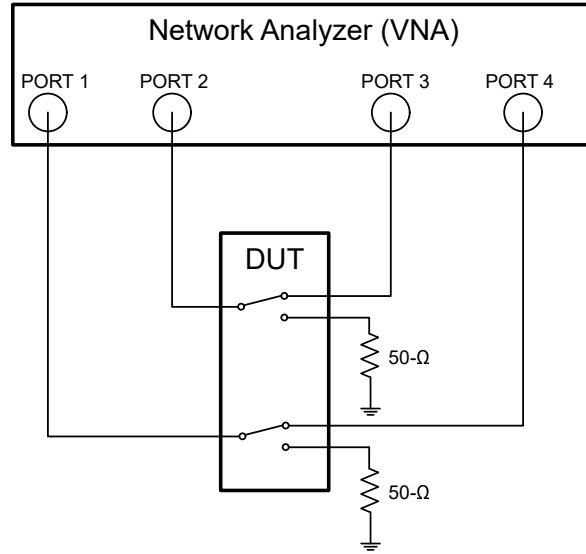


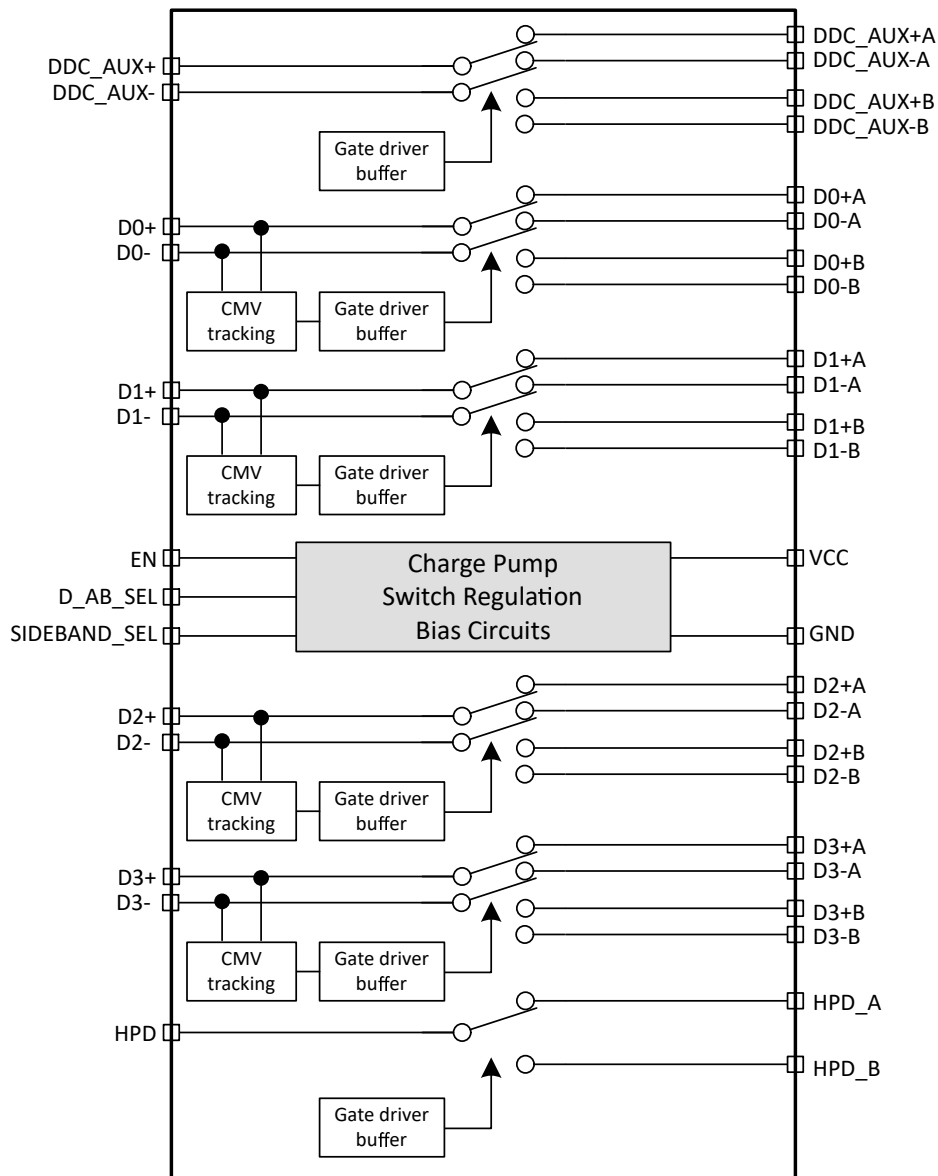
Figure 6-6. Differential Bandwidth (BW), Insertion Loss, and Return Loss

7 Detailed Description

7.1 Overview

The TMUXHS4512 is a protocol agnostic bidirectional multiplexer/demultiplexer that offers low on-state resistance as well as low I/O capacitance, which allows the device to achieve a high bandwidth of 13.0GHz typical for differential channels. The TMUXHS4512 is a passive mux that is recommended for data rates up to 20Gbps. However, the device can be used for interfaces with higher data rates if overall electrical link loss permits. The high-speed data channels of the device provide the high bandwidth necessary for many interfaces to handle differential as well as single-ended signals as long as the single-ended signals do not violate V_{P-N_ABSMAX} . The high-speed channels of the device support differential signaling with common-mode voltage range (CMV) of 0V to 1.0V. The sideband channels are 5V tolerant. The sideband channels support 0V to 1.8V CMOS signals with a typical R_{ON} of 8.5Ω.

7.2 Functional Block Diagram



7.3 Feature Description

The TMUXHS4512 is based on proprietary TI technology which uses FET switches driven by a high-voltage generated from an integrated charge-pump to achieve a low on-state resistance. The TMUXHS4512's low power technology uses only 500 μ A in active and just 2 μ A in powerdown (EN = L) mode. The device has integrated ESD that can support up to 1.5kV Human-Body Model (HBM) and 750V Charge Device Model (CDM). The TMUXHS4512 also has a special feature that prevents the device from back-powering when the V_{CC} supply is not available and an analog signal is applied on the I/O pin. In this situation this special feature prevents leakage current in the device. The TMUXHS4512 is not designed for passing signals with negative swings.

7.4 Device Functional Modes

Table 7-1 lists the device functions for the TMUXHS4512 device.

Table 7-1. Functional Table

| EN | D_AB_SEL | SIDEBAND_SEL | FUNCTION |
|----|----------|--------------|--|
| L | X | X | Switch disabled. All channels are Hi-Z. |
| H | L | L | All A channels are enabled. All B channels are Hi-Z. |
| H | L | H | All A data high-speed channels are enabled and B sideband channels are enabled. All other channels are Hi-Z. |
| H | H | L | All B data high-speed channels are enabled and A sideband channels are enabled. All other channels are Hi-Z. |
| H | H | H | All B channels are enabled. All A channels are Hi-Z. |

8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

The TMUXHS4512 is a generic analog differential passive mux or demux that works for many high-speed differential interfaces with data rates up to 20Gbps. The TMUXHS4512 supports differential signaling with common-mode voltage range (CMV) of 0V to 1.0V and with differential amplitude up to 1600mVpp in Dxx channels. The device can be also used for single-ended CMOS signals with swing limited to 0V to 1.8V in sideband channels. The TMUXHS4512 can be used as mux or demux switch for:

- DisplayPort (DP) for up to UHBR20 for data rates up to 20Gbps
- USB4 and Thunderbolt (TBT) 3 or 4 for data rates up to 20Gbps

8.2 Typical Application - DisplayPort

The TMUXHS4512 can be used to switch DisplayPort signals in both source and sink applications. In source applications DisplayPort port from a graphics processor can be demultiplexed into one of the two connectors or DisplayPort sinks. In a PC the TMUXHS4512 can be used to switch integrated graphics versus discrete graphics to a connector or sink. In a sink application the device also can be used to select between two connectors or DisplayPort sources to provide DisplayPort signals into a scaler (SOC) in sink application. This section provides detailed design implementation for a sink application where TMUXHS4512 provides 2:1 demultiplexing function.

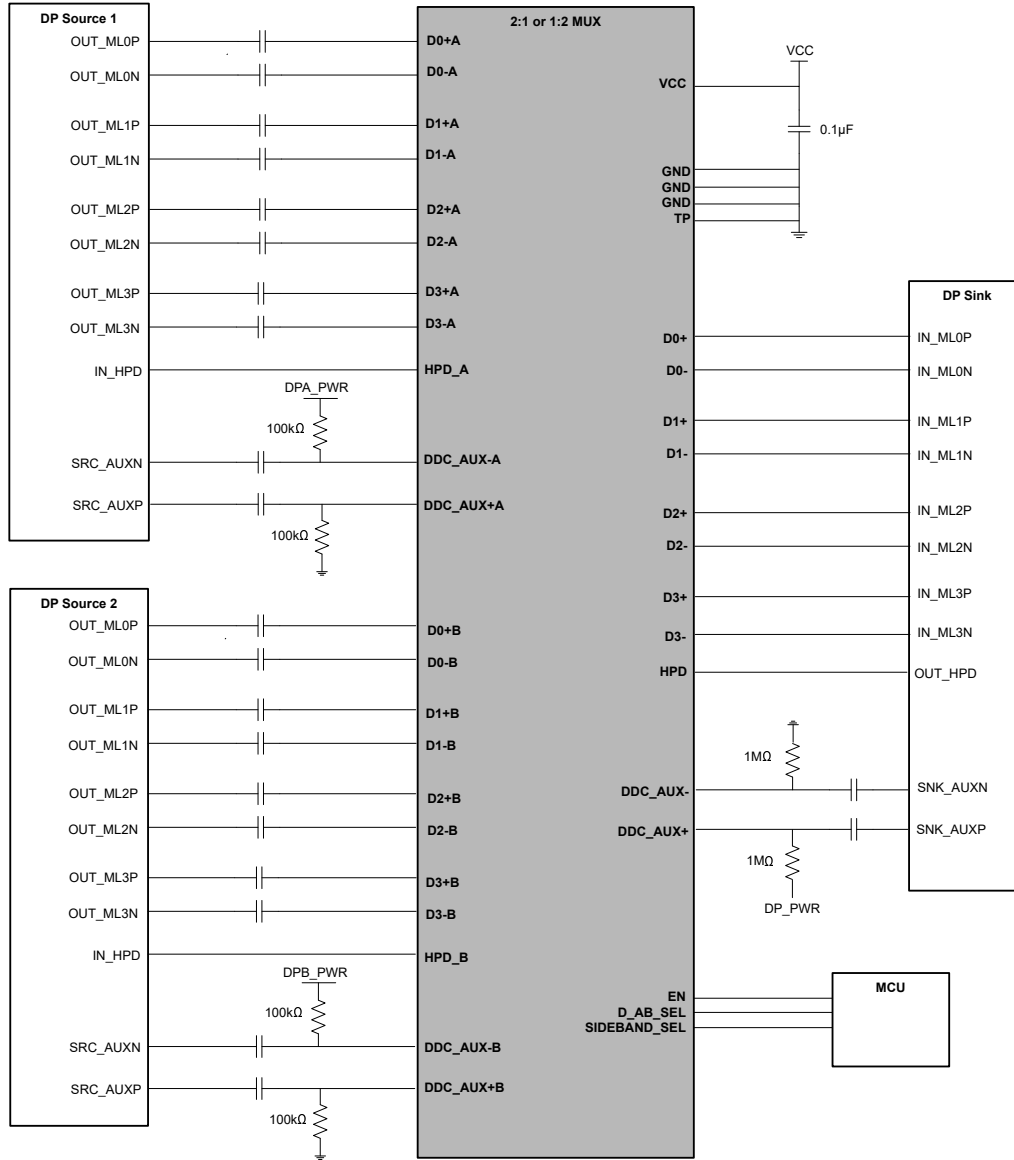


Figure 8-1. Choosing One of Two DisplayPorts - Application Schematic

8.2.1 Design Requirements

Table 8-1 lists the design parameters for this DisplayPort example.

Table 8-1. Design Parameters for DisplayPort Application

| Design parameter | Example value |
|--------------------------|---|
| V _{CC} | 1.62V to 1.98V |
| VCC decoupling capacitor | 0.1μF |
| AUXp resistors | Sink Side: 1MΩ to 3.3V Source Side: 100kΩ to GND |
| AUXn resistors | Sink Side: 1MΩ to GND Source Side: 100kΩ to 3.3V |

8.2.2 Detailed Design Procedure

The TMUXHS4512 is designed to operate with 1.62V to 1.98V power supply. Decoupling capacitors can be used to reduce noise and improve power supply integrity. AUX pullup resistors to 3.3V and pull-down resistors to GND must be placed on the source and sink according to DisplayPort standard.

8.2.3 Application Curves

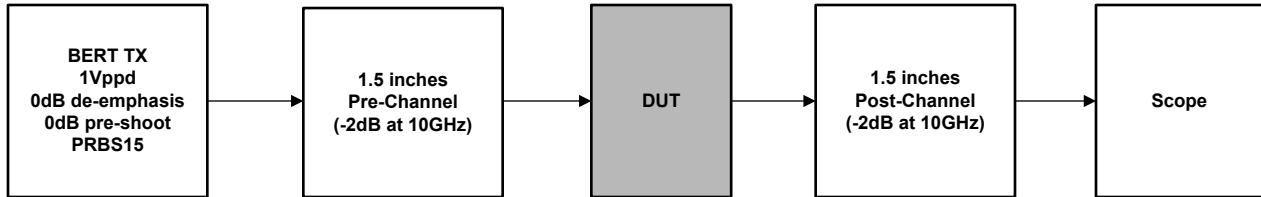
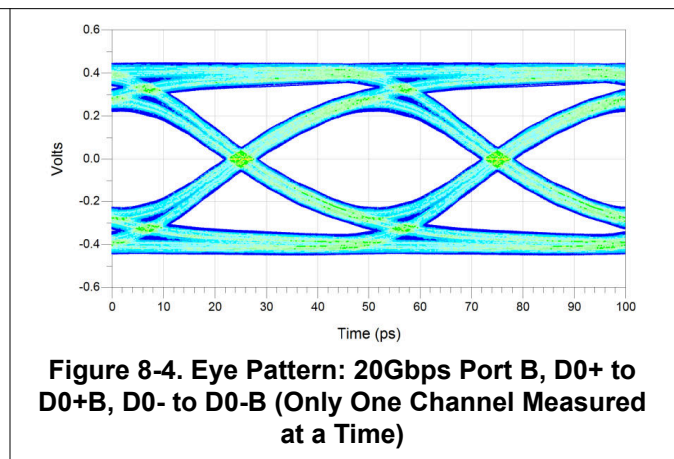
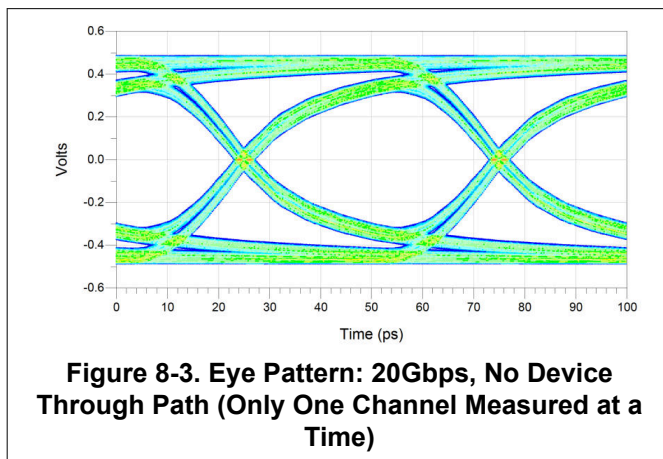


Figure 8-2. Test Setup



8.3 Power Supply Recommendations

Keep the V_{CC} in the range of 1.62V to 1.98V. Do not use voltage levels above those listed in the *Absolute Maximum Ratings* table. Use decoupling capacitors to reduce noise and improve power supply integrity. There are no power sequence requirements for the TMUXHS4512.

8.4 Layout

8.4.1 Layout Guidelines

To ensure reliability of the device, the following commonly used printed circuit board layout guidelines are recommended:

- Use decoupling capacitors between power supply pin and ground pin to ensure low impedance to reduce noise. To achieve a low impedance over a wide frequency range use capacitors with a high self-resonance frequency.
- Place ESD and EMI protection devices (if used) as close as possible to the connector.
- Use short trace lengths to avoid excessive loading.
- Keep traces at least two times the trace width apart to minimize the effects of crosstalk on adjacent traces.
- Separate high-speed signals from low-speed signals and digital from analog signals
- Avoid right-angle bends in a trace and try to route them at least with two 45° corners.
- Route the high-speed differential signal traces parallel to each other as much as possible. The traces are recommended to be symmetrical.
- Place a solid ground plane next to the high-speed signal layer. This also provides an excellent low-inductance path for the return current flow.

8.4.2 Layout Example

The TMUXHS4512 application with a single controller interfacing between a common port and two separate ports.

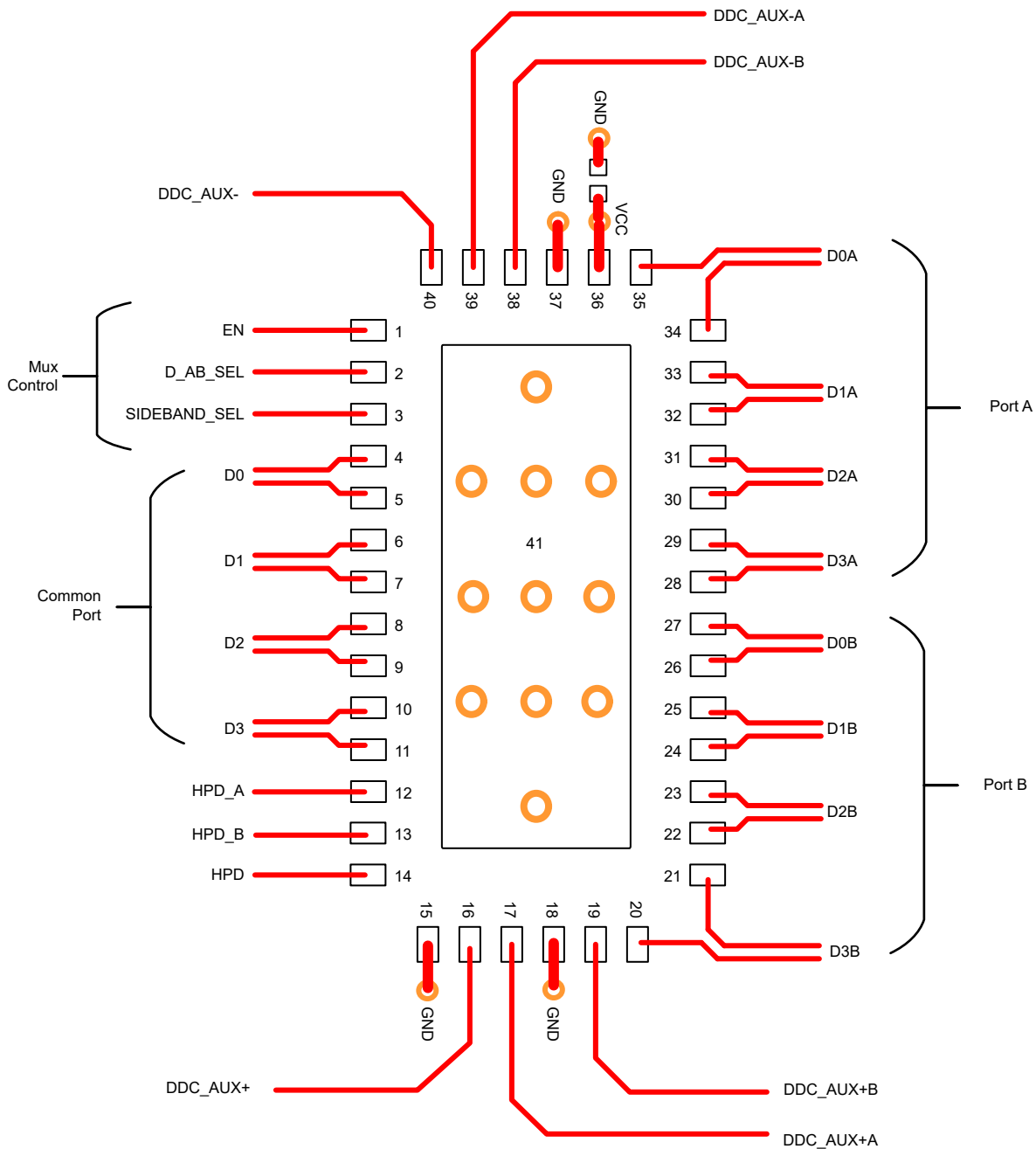


Figure 8-5. Layout Example

8.5 Systems Examples

8.5.1 DisplayPort 1:2 Multiplexing

The TMUXHS4512 supports AC-coupled interfaces such as DisplayPort. External AC-coupling capacitors must be used on either the common side or the non-common side of the device. In this particular example, the external AC-coupling capacitors are placed on the common side. The non-common side is DC-coupled to the DP sinks. The choice of DC-coupling the non-common side or the common side is based on which DP source

or DP sink meets the $V_{IO,CM}$ requirements of the device. If the DP source does not comply to the $V_{IO,CM}$ requirement, then place the AC-coupling capacitors between the DP source and TMUXHS4512. If the DP sink does not comply to the $V_{IO,CM}$ requirement, then place the AC-coupling capacitors between the DP sink and TMUXHS4512.

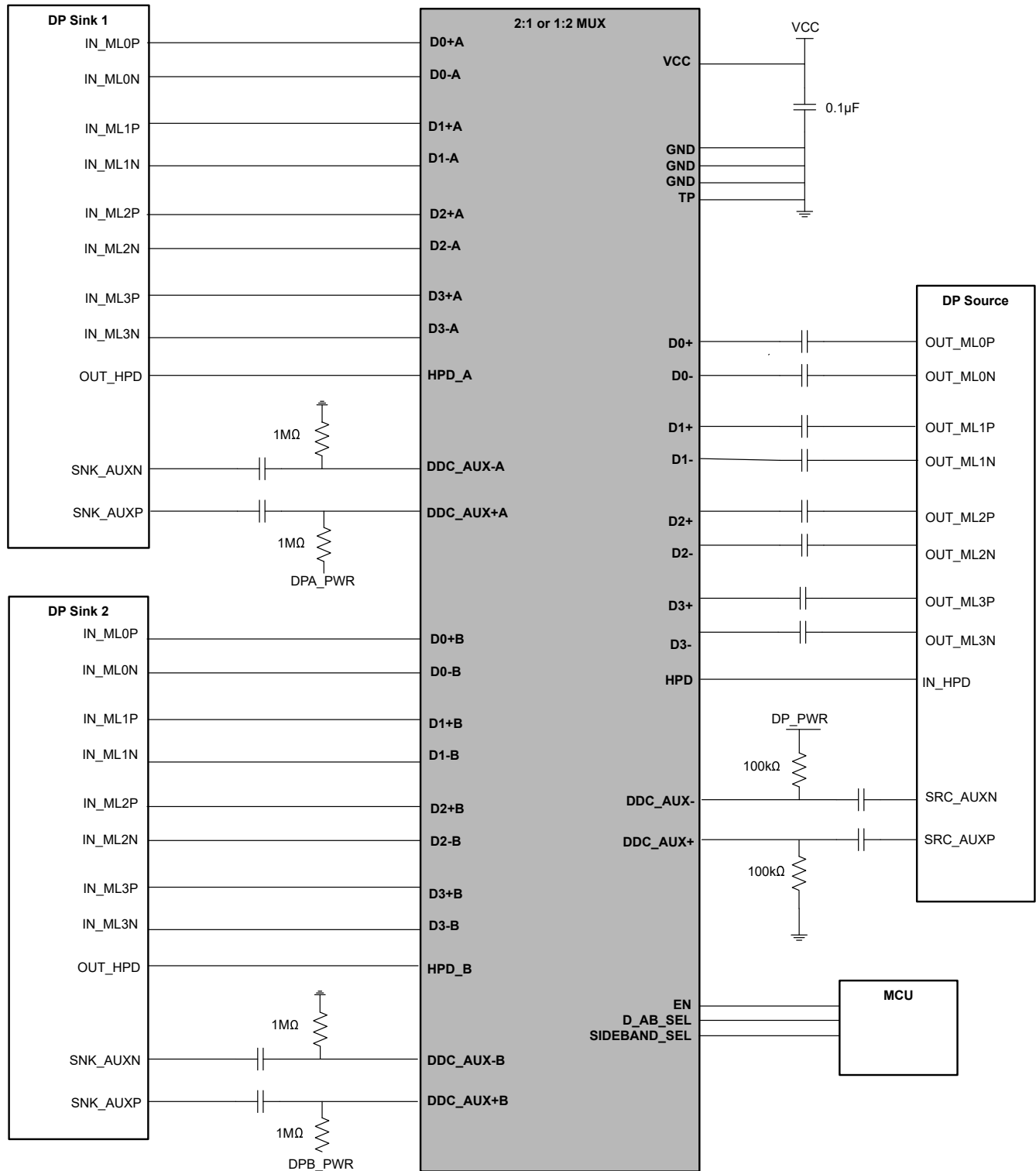


Figure 8-6. DisplayPort 1:2 Switching

9 Device and Documentation Support

9.1 Documentation Support

9.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, [Implications of Slow or Floating CMOS Inputs application note](#).

9.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on [ti.com](#). Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.3 Support Resources

[TI E2E™ support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

9.4 Trademarks

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9.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.6 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

10 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| DATE | REVISION | NOTES |
|---------------|----------|-----------------|
| November 2024 | * | Initial Release |

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead finish/ Ball material (6) | MSL Peak Temp (3) | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|---------------|--------------|-----------------|------|-------------|-----------------|--------------------------------------|----------------------|--------------|-------------------------|-------------------------|
| TMUXHS4512IRETR | ACTIVE | WQFN | RET | 40 | 3000 | RoHS & Green | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | TMX412 | Samples |
| TMUXHS4512IRETT | ACTIVE | WQFN | RET | 40 | 250 | RoHS & Green | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | TMX412 | Samples |
| TMUXHS4512RETR | ACTIVE | WQFN | RET | 40 | 3000 | RoHS & Green | NIPDAU | Level-2-260C-1 YEAR | 0 to 105 | TMX412 | Samples |
| TMUXHS4512RETT | ACTIVE | WQFN | RET | 40 | 250 | RoHS & Green | NIPDAU | Level-2-260C-1 YEAR | 0 to 105 | TMX412 | Samples |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSELETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|-----------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| TMUXHS4512IRETR | WQFN | RET | 40 | 3000 | 330.0 | 12.4 | 3.3 | 6.3 | 1.05 | 8.0 | 12.0 | Q1 |
| TMUXHS4512IRETT | WQFN | RET | 40 | 250 | 180.0 | 12.4 | 3.3 | 6.3 | 1.05 | 8.0 | 12.0 | Q1 |
| TMUXHS4512RETR | WQFN | RET | 40 | 3000 | 330.0 | 12.4 | 3.3 | 6.3 | 1.05 | 8.0 | 12.0 | Q1 |
| TMUXHS4512RETT | WQFN | RET | 40 | 250 | 180.0 | 12.4 | 3.3 | 6.3 | 1.05 | 8.0 | 12.0 | Q1 |

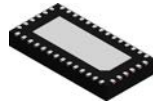
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|-----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TMUXHS4512IRETR | WQFN | RET | 40 | 3000 | 367.0 | 367.0 | 38.0 |
| TMUXHS4512IRETT | WQFN | RET | 40 | 250 | 213.0 | 191.0 | 35.0 |
| TMUXHS4512RETR | WQFN | RET | 40 | 3000 | 367.0 | 367.0 | 38.0 |
| TMUXHS4512RETT | WQFN | RET | 40 | 250 | 213.0 | 191.0 | 35.0 |

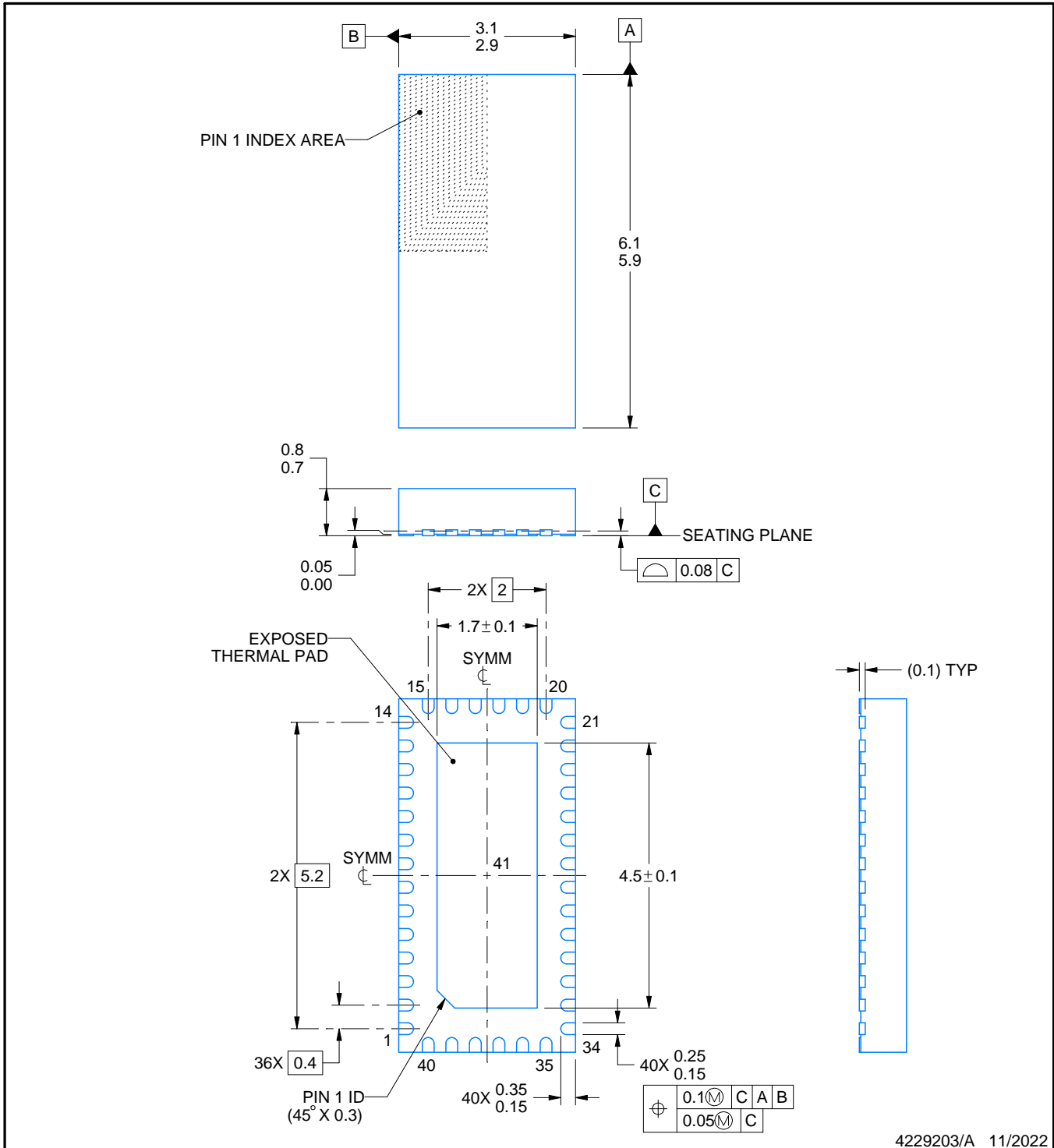
RET0040A



PACKAGE OUTLINE

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



4229203/A 11/2022

NOTES:

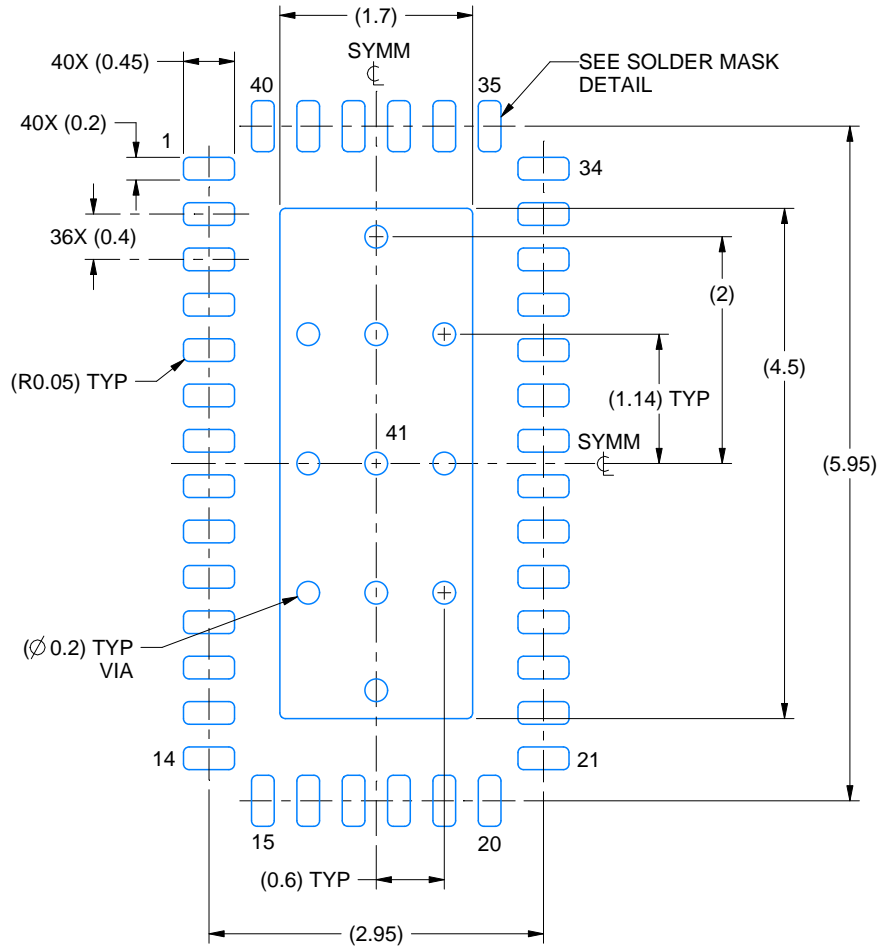
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

EXAMPLE BOARD LAYOUT

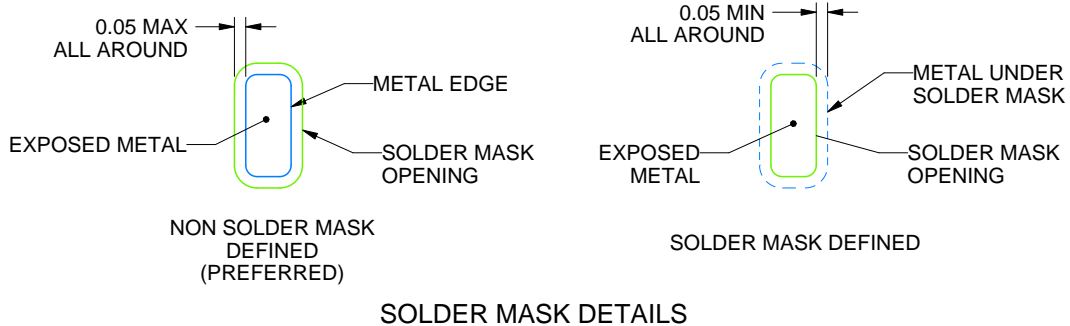
RET0040A

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X



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NOTES: (continued)

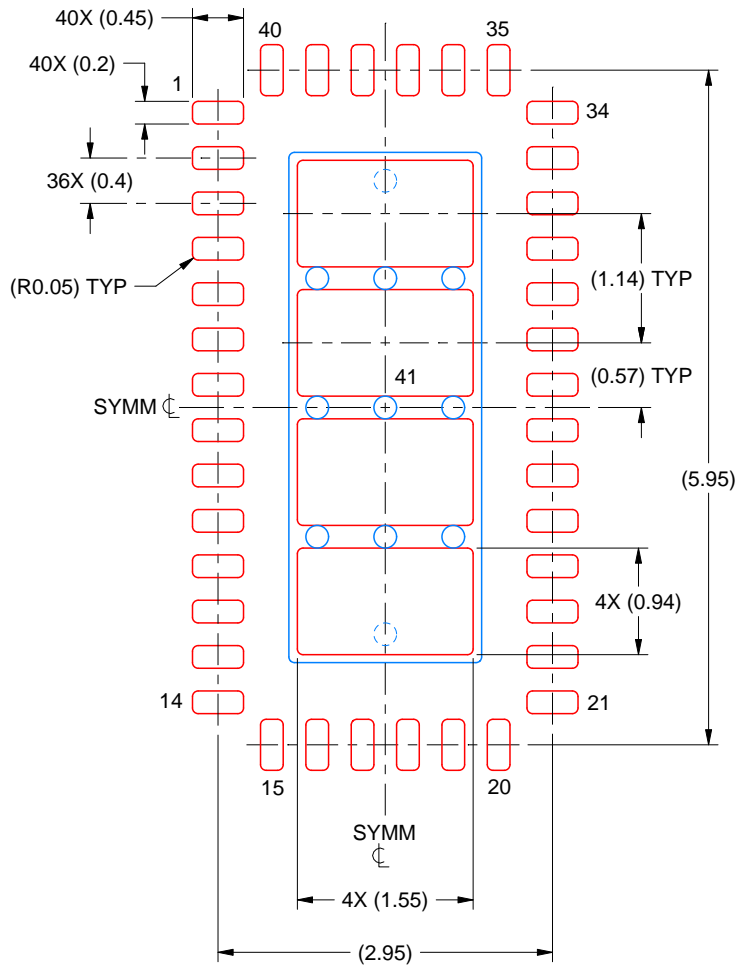
- This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

RET0040A

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.125 MM THICK STENCIL
SCALE: 15X

EXPOSED PAD 41
76% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE

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NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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